



Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 45V

Forward Current - 5.0A

FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: SMAF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 27mg / 0.00095oz

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Top View

Marking Code: SS545

Simplified outline SMAF and symbol

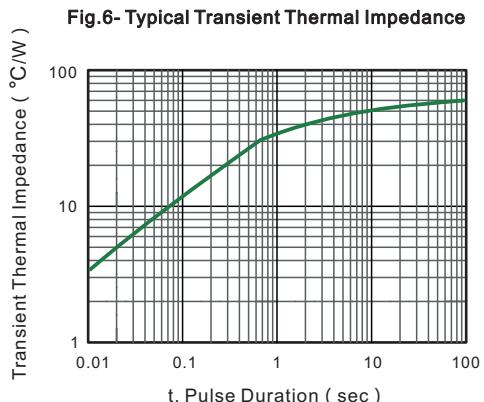
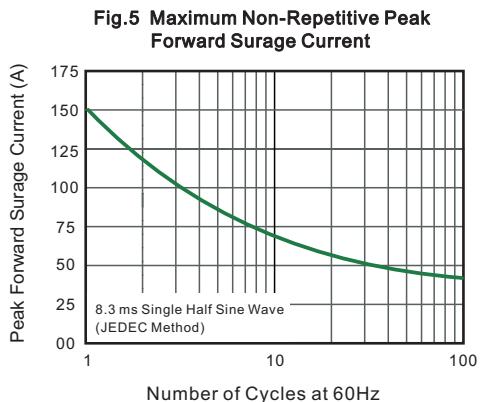
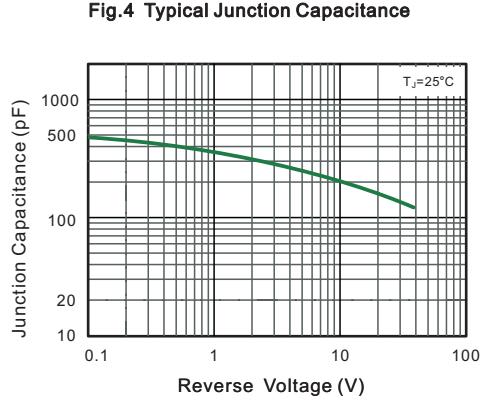
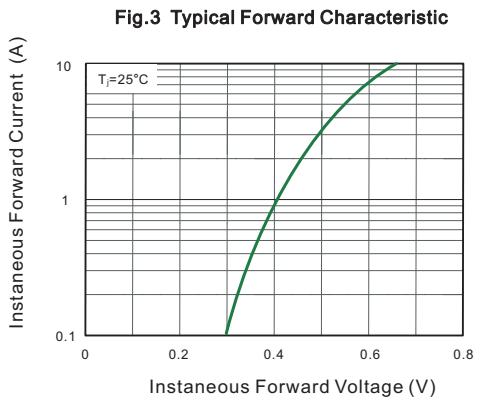
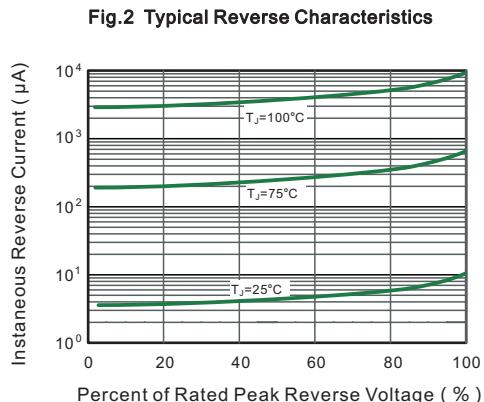
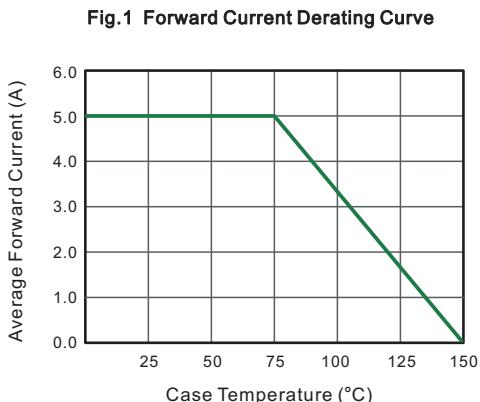
Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	SS545F	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	45	V
Maximum RMS voltage	V_{RMS}	32	V
Maximum DC Blocking Voltage	V_{DC}	45	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	5.0	A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150	A
Max Instantaneous Forward Voltage at 5 A	V_F	0.55	V
Maximum DC Reverse Current $T_j = 25^\circ C$ at Rated DC Reverse Voltage $T_j = 100^\circ C$	I_R	1 50	mA
Typical Junction Capacitance ⁽¹⁾	C_J	400	pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	60	°C/W
Operating Junction Temperature Range	T_j	-55 ~ +150	°C
Storage Temperature Range	T_{stg}	-55 ~ +150	°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

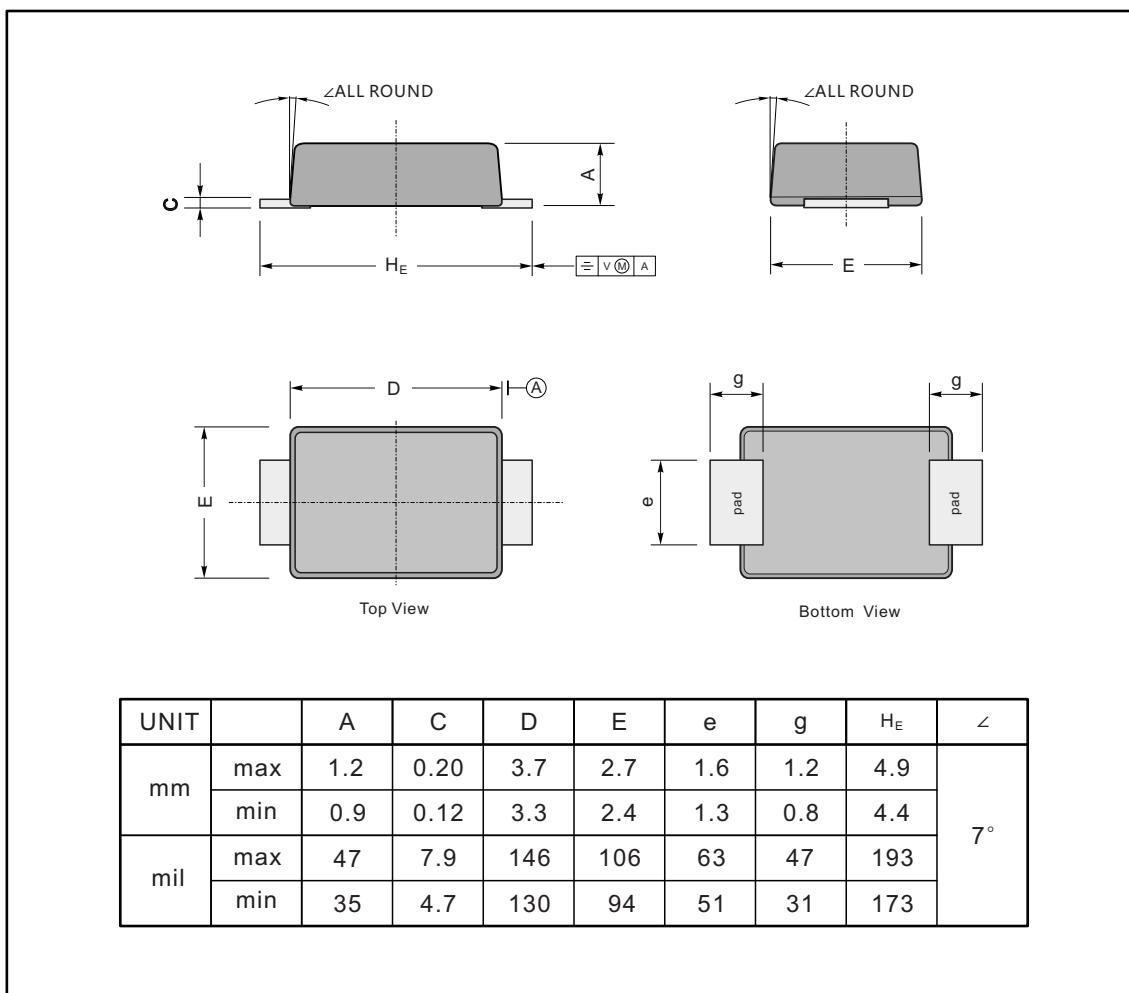




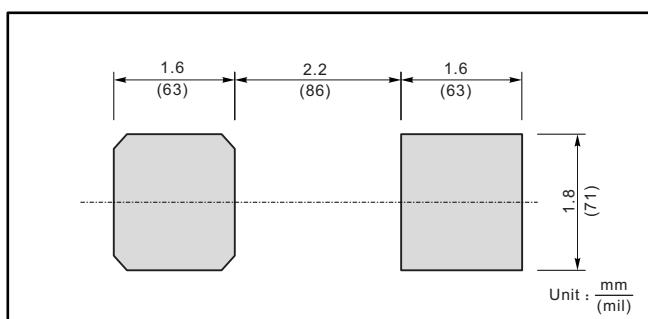
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SMAF



The recommended mounting pad size



Marking

Type number	Marking code
SS545F	SS545